MC3100/MC3000 series

8-INPUT "NAND" GATE

MC3116F • MC3016F MC3116L • MC3016L,P (54H30J) (74H30J, N)

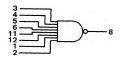
2.8 k 760 58

3 0 4.0 k 58

6 0 11 0 12 0 7

7 Gnd

This device is an 8-input NAND gate. It is useful when processing a large number of variables, such as in encoders and decoders.



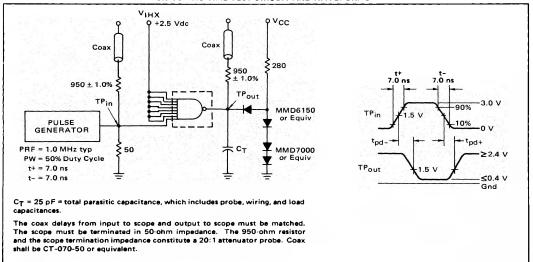
Positive Logic: 8 = 3 • 4 • 5 • 6 • 11 • 12 • 1 • 2 Negative Logic: 8 = 3 + 4 + 5 + 6 + 11 + 12 + 1 + 2

Input Loading Factor = 1
Output Loading Factor = 10
Total Power Dissipation = 22 mW typ/pkg
Propagation Delay Time = 8.0 ns typ

Pin numbers for the 54H30F/74H30F device are shown in the chart. These devices are available on special request.

DEVICE						PIN	NU	MBE	RS					
MC3116F,L/3016F,L,P	1	2	3	4	5	6	7	8	9	10	11	12	13	14
54H30F/74H30F	9	10	2	3	5	6	11	12	1	14	7	8	13	4

SWITCHING TIME TEST CIRCUIT AND WAVEFORMS

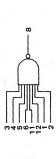


General Information section for packaging.

MC3116, MC3016 (continued)

ELECTRICAL CHARACTERISTICS

Test procedures are shown for only one input of this device. To complete testing, sequence through remaining inputs in the same manner.



															_					_	EST CL	RRENT	TEST CURRENT/VOLTAGE VALUES	/ALUES						
														@ Tect	L t		mA		H					Volts						
														Temperature	ture		_₹	5	٥	У _В	™	> =	_	V _{RH}	> ×em	۸ در ۷	Vcct	V _{CCH} V	VIHX	
														_	55°C	50	-2.0	1	-	1.1 2.	0.0	4 2.	4	4.0		5.0	4.5 5	5.5		
													MC3116	~	+25°C	50	-2.0	1.0	-10 1	1.1	1.8 0.4	4 2.4	-	4.0	7.0	5.0	4.5 5	5.5	2.5	
														+	+125°C	20	-2.0	-	- 0	0.8 1	1.8 0.4	4 2.4	_	4.0		5.0 9	4.5 5	5.5		
														_	٥ ا	20	-2.0	,	-	1.1 2.	2.0 0.4	2.	5	4.0	,	5.0 4	4.75 5.	5.25		
													MC3016	~	+25°C	20	-2.0	1.0	-10 1	1.1	1.8 0.4	4 2.5	-	4.0	7.0	5.0 4	4.75 5.	5.25 2	2.5	
														+	+75°C	20	-2.0	,	-	0.9	1.8 0.4	4 2.5		4.0	,	5.0 4	4.75 5	5.25		
		Pin		MC	MC3116 Test Li	est Limi	mits			MC	3016 Te	MC3016 Test Limits							TEST C	URREN	r / VOL:	TAGE AP	EST CURRENT / VOLTAGE APPLIED TO PINS LISTED BELOW	PINS LISTE	D BELOV	٧.				
		Under	-5	−55°C	+25°C	S°C	+12	+125°C	00	ی	+25°C	ؠ	+75°C	ر	1	1	1.	+	1	1	F	F	F	F	1		-	-	T	
Characteristic	Symbol	Test	Min	Min Max	Win	Max	Min	Min Max	Win	Max	Win	Max	Min	Max	Unit	٥	¥	_E	0	> "	۸ ۲	4	N N	V _{RH}	Vmax	ν ος	Vcc1	V _{CCH}	VIHX	Gud
Input Forward Current	I.	60		-2.0		-2.0	•	-2.0	•	-2.0		-2.0	-	-2.0 n	mAdc	,			-	-	8	-		1, 2, 4, 5, 6, 11, 12		-	,	14	-	1
Leakage Current	$^{\rm I_R}$	60		20		20		20		20		20	,	20 4	μAdc	,						8			,	,	1	14	- 1,	1, 2, 4, 5, 6, 7, 11, 12
Breakdown Voltage	BVin	6		,	5.5	1	,	1			5.5		,		Vdc			8		-		1			,	,		14	1,	1, 2, 4, 5, 6, 7, 11, 12
Clamp Voltage	v _D	60			1	-1.5	,					-1.5	,	-	Vdc		,	,	60		,	-			,		14	,		-
Output Output Voltage	TO _A	ω		0.4	- 1"	0.4	,	0.4		0.4	1	9.4	,	0.4	Vdc	80	-	-		-	- 8	'		1, 2, 4, 5 6, 11, 12	,		14	,		7
	ио,	8	2.4		2.4	1	2.4		2.5		2.5		2.5		Vdc		80		,	8		'		1, 2, 4, 5, 6, 11, 12		,	14			-
Short-Circuit Current	¹sc	œ	-40	-100	-40	-100	-40	-100	-40	-100	-40	-100	-40	-100 n	mAdc	,			,			'			,	,		14	1,2	,2,3,4,5,8, 8,11,12
Power Requirements (Total Device) Maximum Power Supply Current	Imax	14			,	6.5	1	-	1	,	1	6.5	,	ı	mAdc		,	,			'	,			14		,	,	1,	1, 2, 3, 4. 5, 7, 11, 12
Power Supply Drain	HOd	14	-	10	,	10	1	10	•	10	,	10	,	10 m	mAdc	-	,		-		1	,		1,2,3,4,		,	,	14		7
	Igq	14		4.2	,	4.2	,	4.2	ï	4.2	,	4.2		4.2 m	mAdc			,			,	'						14	- 1,1	1,2,3,4,5,
Switching Parameters															-		Pulse	-	-	-	-	<u>. </u>	-			-			1,2,4,5,	
Turn-On Delay	tpd-	3,8		ı.	,	12		, .			,	12		,	su	09	80	ı	,		1					14		- 6,1	11, 12	-
Turn-Off Delay	tpd+	3,8		1	,	10		,			-	10	,	,	su	3	80			-		-		-		14	,	1,2	1,2,4,5,	1